

Phase-out/Discontinued

2SJ324,324-Z

SWITCHING
P-CHANNEL POWER MOS FET

DESCRIPTION

The 2SJ324 is P-channel MOS Field Effect Transistor designed for solenoid, motor and lamp driver.

FEATURES

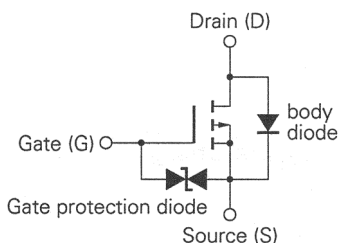
- Low On-state Resistance
 $R_{DS(on)} = 0.18 \Omega$ TYP. ($V_{GS} = -10$ V, $I_D = -1.0$ A)
 $R_{DS(on)} = 0.36 \Omega$ TYP. ($V_{GS} = -4$ V, $I_D = -0.8$ A)
- Low C_{iss} : $C_{iss} = 330$ pF TYP.
- Built-in G-S Gate Protection Diode

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

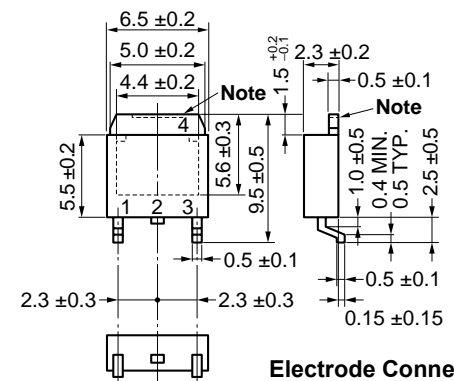
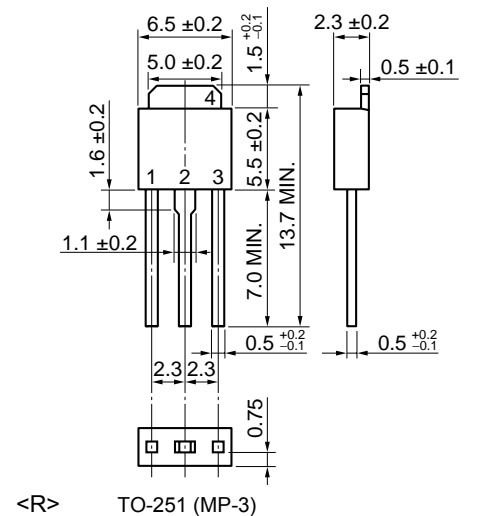
Drain to Source Voltage	V_{DSS}	-30	V
Gate to Source Voltage (AC)	V_{GSS}	± 20	V
Gate to Source Voltage (DC)	V_{GSS}	-20, +10	V
Drain Current (DC)	$I_{D(DC)}$	± 2.0	A
Drain Current (pulse) ^{Note}	$I_{D(pulse)}$	± 8.0	A
Total Power Dissipation ($T_C = 25^\circ\text{C}$)	P_{T1}	20	W
Total Power Dissipation ($T_A = 25^\circ\text{C}$)	P_{T2}	1.0	W
Channel Temperature	T_{ch}	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Note $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$

EQUIVALENT CIRCUIT



PACKAGE DRAWINGS (Unit: mm)



Electrode Connection

1. Gate
2. Drain
3. Source
4. Drain Fin

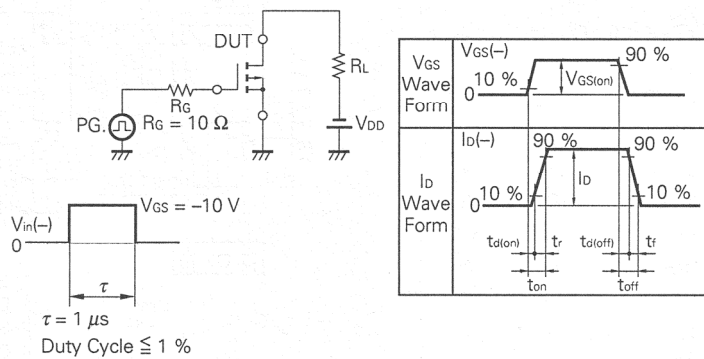
Note The depth of notch at the top of the fin is from 0 to 0.2 mm.

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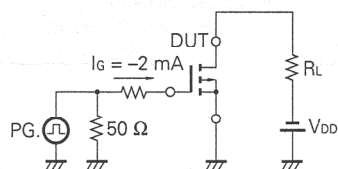
ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-state Resistance	R _{DS(on)}		0.18	0.25	Ω	V _{GS} = -10 V, I _D = -1.0 A
Drain to Source On-state Resistance	R _{DS(on)}		0.36	0.52	Ω	V _{GS} = -4 V, I _D = -0.8 A
Gate to Source Cutoff Voltage	V _{GS(off)}	-1.0	-1.5	-2.0	V	V _{DS} = -10 V, I _D = -1 mA
Forward Transfer Admittance	y _{fs}	1.0	1.9		S	V _{DS} = -10 V, I _D = -1.0 A
Drain Leakage Current	I _{DSS}			-10	μA	V _{DS} = -30 V, V _{GS} = 0
Gate to Source Leakage Current	I _{GSS}			±10	μA	V _{GS} = ±16 V, V _{DS} = 0
Input Capacitance	C _{iss}		330		pF	V _{DS} = -10 V V _{GS} = 0 f = 1 MHz
Output Capacitance	C _{oss}		290		pF	
Reverse Transfer Capacitance	C _{rss}		105		pF	
Turn-On Delay Time	t _{d(on)}		7		ns	V _{GS(on)} = -10 V V _{DD} = -15 V I _D = -1.0 A, R _G = 10 Ω R _L = 15 Ω
Rise Time	t _r		35		ns	
Turn-Off Delay Time	t _{d(off)}		40		ns	
Fall Time	t _f		30		ns	
Total Gate Charge	Q _G		12		nC	V _{GS} = -10 V I _D = -2.0 A V _{DD} = -24 V
Gate to Source Charge	Q _{GS}		1.5		nC	
Gate to Drain Charge	Q _{GD}		4.5		nC	
Body Diode Forward Voltage	V _F		0.9		V	I _F = 2.0 A, V _{GS} = 0
Reverse Recovery Time	t _{rr}		50		ns	I _F = 2.0 A, V _{GS} = 0 di/dt = 50 A/μs
Reverse Recovery Charge	Q _{rr}		40		nC	
ESD	V _{ESD}		±130		V	C = 200 pF, R = 0, Single Pulse

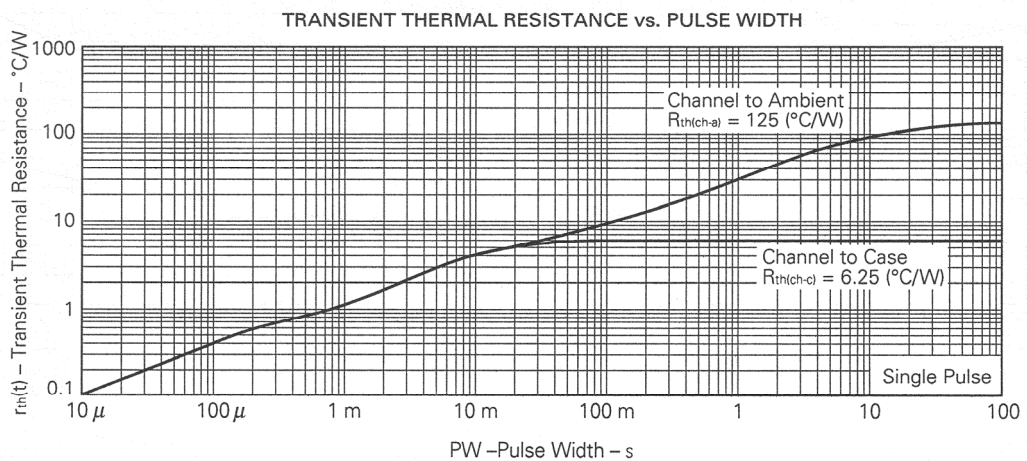
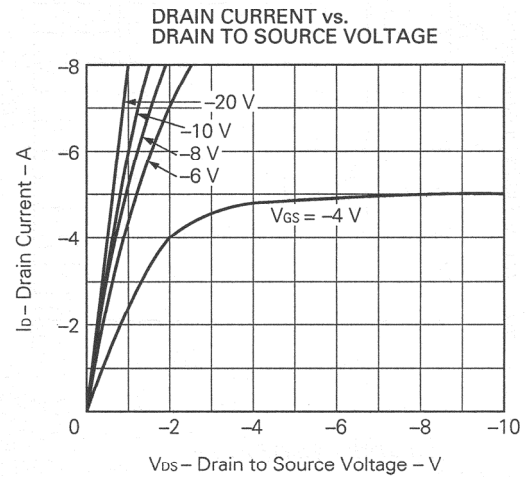
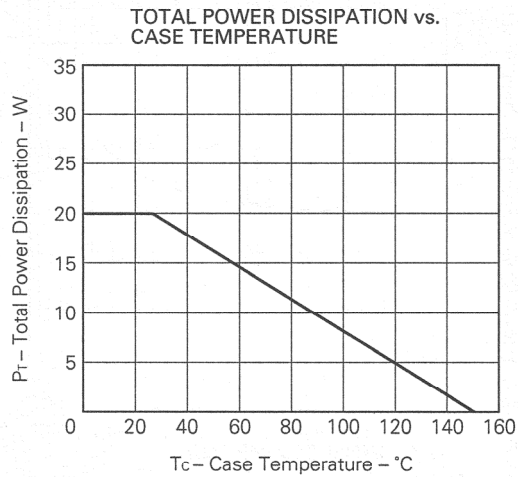
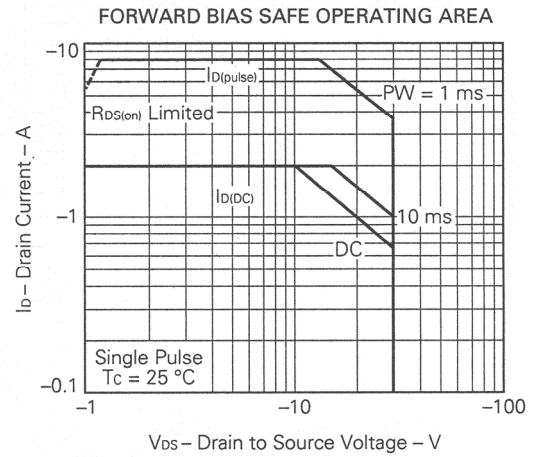
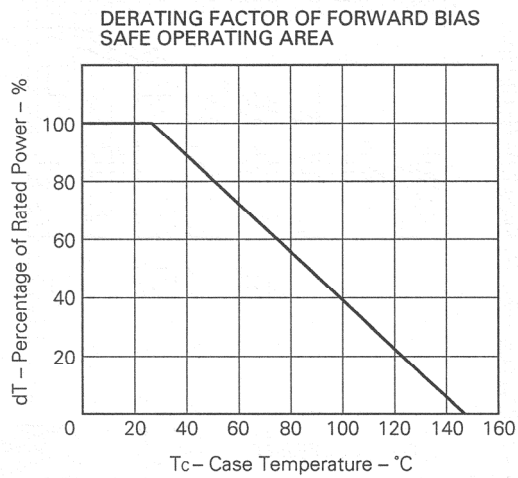
Test Circuit 1: Switching Time



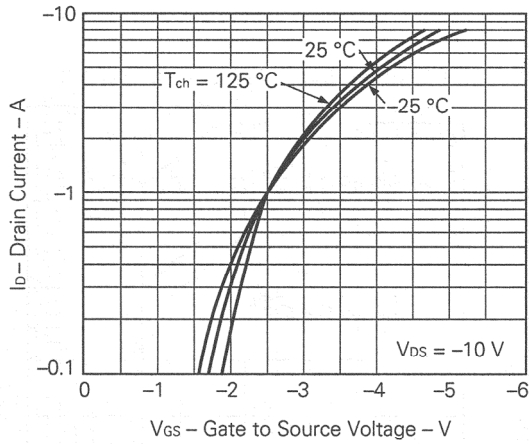
Test Circuit 2: Gate Charge



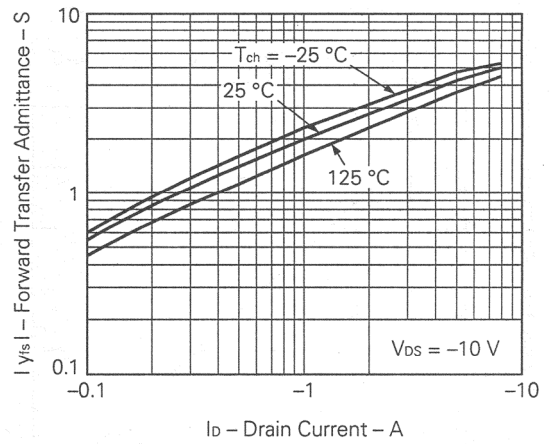
TYPICAL CHARACTERISTICS ($T_a = 25\text{ }^{\circ}\text{C}$)



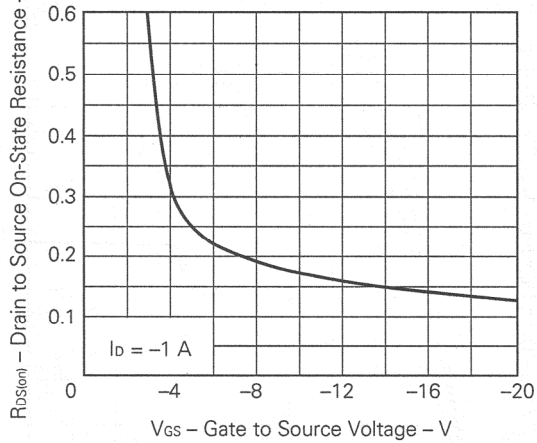
TRANSFER CHARACTERISTICS



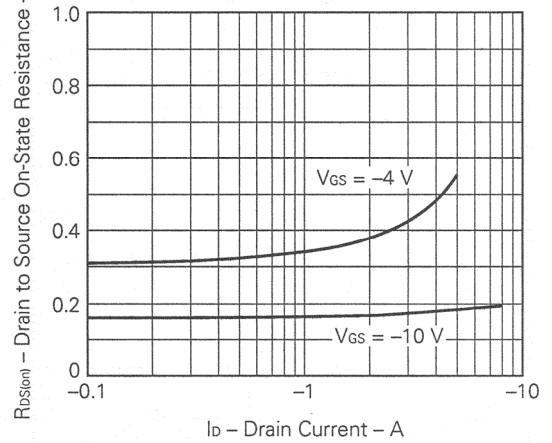
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



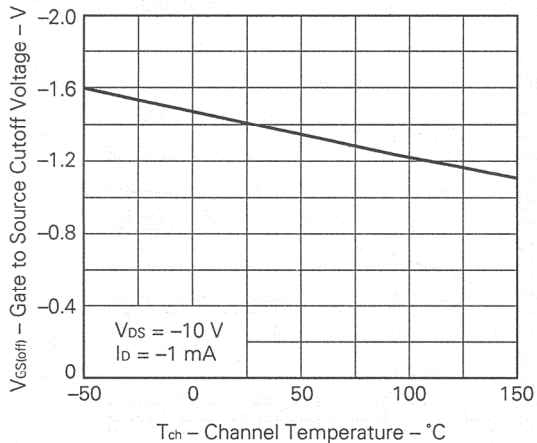
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



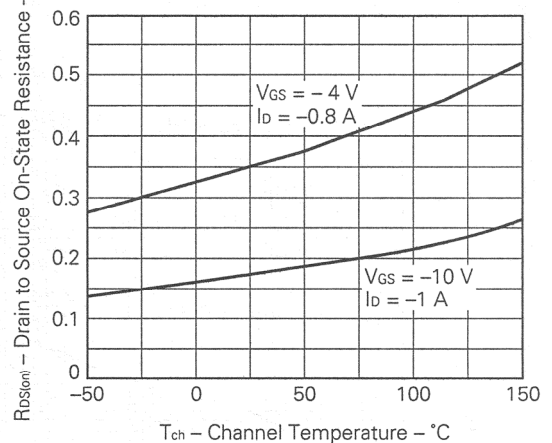
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

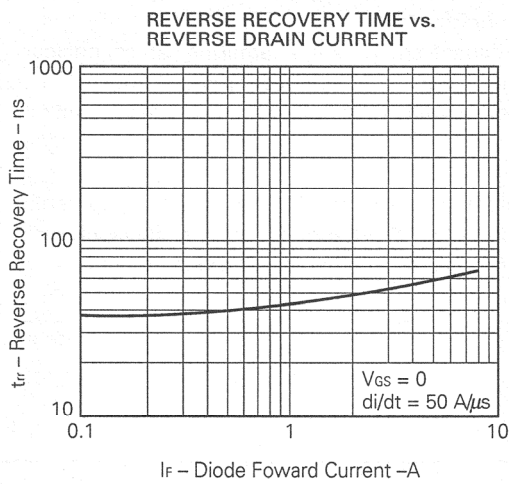
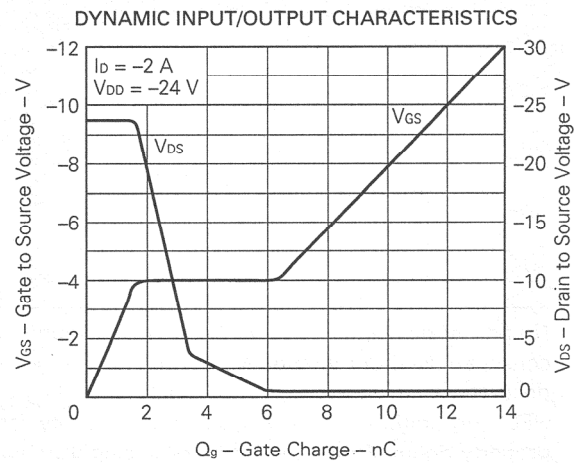
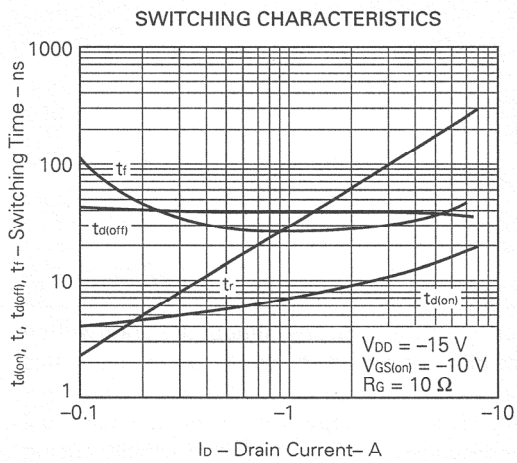
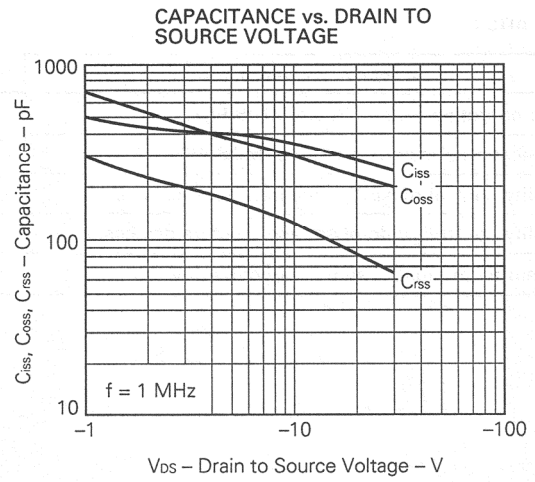
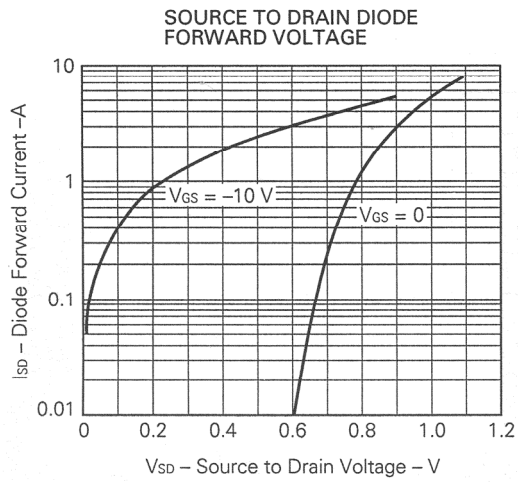


GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE



DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE





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